

CRMKTH0202A N-Channel 22V, 2.1mΩ Typ. Power MOSFET

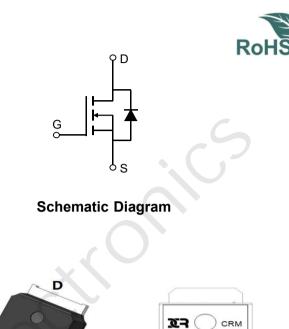
Description

Features

• 22V, 115A

 $R_{DS(ON)}$ Typ = 2.1m Ω @ V_{GS} = 10V

- Advanced Trench Technology
- Excellent R_{DS(ON)} and Low Gate Charge
- 100% UIS TESTED!
- 100% ΔVds TESTED!



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Application

- Load Switch
- PWM Application
- Power Management

Marking and Pin Assignment

Package Marking and Ordering Information

Device	Marking	Package	Outline	Reel Size	Reel (pcs)	Per Carton (pcs)
CRMKTH0202A	CRMKTH0202A	TO-252-3L	TAPING	13"	2500	25000

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Absolute Maximum Ratings (@ T_J = 25°C unless otherwise specified)

Symbol	Parameter		Value	Units
V _{DS}	Drain-to-Source Voltage		22	V
V _{GS}	Gate-to-Source Voltage		±20	V
	Continuous Drain Current	$T_{C} = 25^{\circ}C$	115	А
Ι _D		T _C = 100°C	69	А
I _{DM}	Pulsed Drain Current ⁽¹⁾		460	А
E _{AS}	Single Pulsed Avalanche Energy ⁽²⁾		196	mJ
P _D	Power Dissipation	T _C = 25°C	62.5	W
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction to Case		2	°C/W
T_{J}, T_{STG}	Junction & Storage Temperature Range		-55 to 150	°C



Electrical Characteristics (T_J = 25°C unless otherwise specified)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
Off Chara	acteristics					
V _{(BR)DSS}	Drain-Source Breakdown Voltage	$I_{D} = 250 \mu A, V_{GS} = 0 V$	22	-	-	V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 22V, V _{GS} = 0V	-	-	1.0	μA
I _{GSS}	Gate-Body Leakage Current	$V_{DS} = 0V, V_{GS} = \pm 20V$	-	-	±100	nA
On Chara	acteristics				6	
V _{GS(th)}	Gate Threshold Voltage	V_{DS} = V_{GS} , I_D = 250 μ A	1.7	2.2	2.7	V
R _{DS(ON)}	Static Drain-Source ON-Resistance ⁽³⁾	V _{GS} = 10V, I _D = 20A	-	2.1	2.73	mΩ
Dynamic	Characteristics					
C _{iss}	Input Capacitance		-	3578	-	pF
C_{oss}	Output Capacitance	V _{GS} = 0V, V _{DS} = 10V, f = 1MHz	-	717	-	pF
C _{rss}	Reverse Transfer Capacitance	1 - 110112	Χ-	487	-	pF
Q _g	Total Gate Charge	(-	43	-	nC
Q_{gs}	Gate Source Charge	$V_{GS} = 0$ to 10V $V_{DS} = 10V$, $I_{D} = 30A$	9.	8	-	nC
Q_{gd}	Gate Drain("Miller") Charge	v _{DS} = 10v, i _D = 30A	-	13	-	nC
Switchin	g Characteristics					
t _{d(on)}	Turn-On DelayTime		-	14	-	ns
t _r	Turn-On Rise Time	V _{GS} = 10V, V _{DD} = 10V	-	32	-	ns
$t_{d(off)}$	Turn-Off DelayTime	I_D = 30A, R_{GEN} = 3 Ω	-	78	-	ns
t _f	Turn-Off Fall Time		-	80	-	ns
Drain-So	urce Diode Characteristics and M	lax Ratings				
I _S	Maximum Continuous Drain to Source Diode Forward Current			-	115	А
I _{SM}	Maximum Pulsed Drain to Source Diode Forward Current		-	-	460	А
V_{SD}	Drain to Source Diode Forward Voltage	V _{GS} = 0V, I _S = 20A	-	-	1.2	V
trr	Body Diode Reverse Recovery Time		-	15	-	ns
Qrr	Body Diode Reverse Recovery Charge	I _F = 20A, di/dt = 100A/us	-	8	-	nC

Notes:

1. Repetitive Rating: Pulse Width Limited by Maximum Junction Temperature.

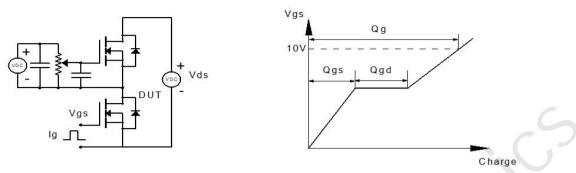
2. E_{AS} condition: Starting T_J=25°C, V_{DD}=10V, V_G=10V, R_G=250hm, L=0.5mH, I_{AS}=28A

3. Pulse Test: Pulse Width \leqslant 300µs, Duty Cycle \leqslant 0.5%.



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Test Circuit





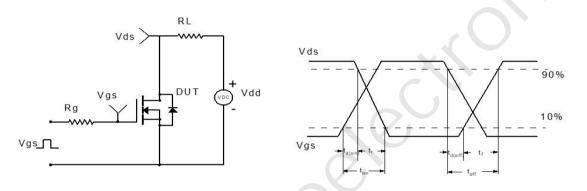
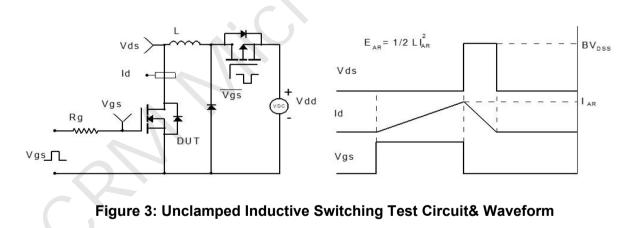


Figure 2: Resistive Switching Test Circuit & Waveform



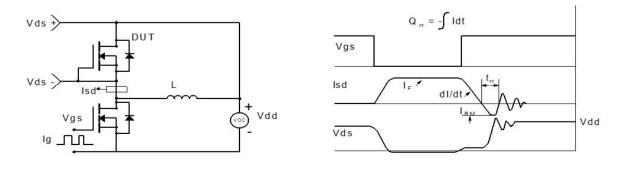
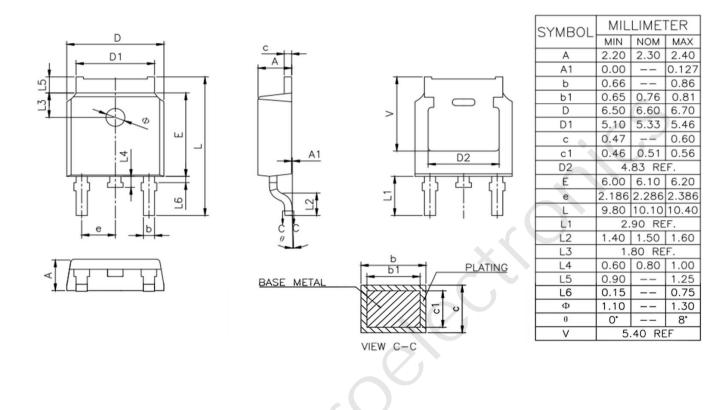


Figure 4: Diode Recovery Test Circuit & Waveform



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Package Mechanical Data(TO-252-3L)



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